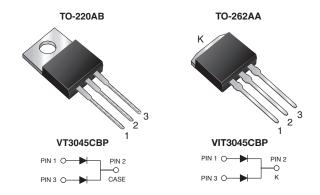


Vishay General Semiconductor

TMBS® (Trench MOS Barrier Schottky) Rectifier for PV Solar Cell Bypass Protection

Ultra Low $V_F = 0.30 \text{ V}$ at $I_F = 5.0 \text{ A}$



| PRIMARY CHARACTERISTICS | | | | | |
|--|--------------------|--|--|--|--|
| I _{F(AV)} | 2 x 15 A | | | | |
| V _{RRM} | 45 V | | | | |
| I _{FSM} | 200 A | | | | |
| V _F at I _F = 15 A | 0.39 V | | | | |
| T _{OP} max. (AC mode) | 150 °C | | | | |
| T _J max. (DC forward current) | 200 °C | | | | |
| Package | TO-220AB, TO-262AA | | | | |
| Circuit configurations | Common cathode | | | | |

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses

• High efficiency operation

• Solder dip 275 °C max. 10 s, per JESD 22-B106

06 HALOGEN

- T_J 200 °C max. in solar bypass mode application
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

MECHANICAL DATA

Case: TO-220AB, TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | | |
|--|------------------|------------------------------------|-------------|------|----|--|
| PARAMETER | SYMBOL | VT3045CBP | VIT3045CBP | UNIT | | |
| Maximum repetitive peak reverse voltage | | V_{RRM} | 45 | | V | |
| Maximum average forward rectified current (fig. 1) | per device | I _{F(AV)} (1) | 30 | | А | |
| | per diode | | 15 | | | |
| Peak forward surge current 8.3 ms single half sine-way on rated load per diode | I _{FSM} | 200 | | Α | | |
| Operating junction and storage temperature range (AC mode) | | T _{OP} , T _{STG} | -40 to +150 | | °C | |
| Junction temperature in DC forward current without reverse bias, $t \leq 1\ h$ | | T _J ⁽²⁾ | ≤ 2 | 00 | °C | |

Notes

⁽²⁾ Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test

| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | | |
|---|---|-------------------------------|-------------------------------|------|------|------|--|
| PARAMETER | TEST CONDITIONS SYM | | SYMBOL | TYP. | MAX. | UNIT | |
| Instantaneous forward voltage per diode | I _F = 5 A | T _A = 25 °C | V _F ⁽¹⁾ | 0.42 | = | V | |
| | I _F = 7.5 A | | | 0.44 | - | | |
| | I _F = 15 A | | | 0.49 | 0.57 | | |
| | I _F = 5 A | | | 0.30 | - | | |
| | I _F = 7.5 A | | | 0.33 | - | | |
| | I _F = 15 A | | | 0.39 | 0.48 | | |
| Reverse current per diode | V - 45 V | T _A = 25 °C | 1 (2) | = | 2000 | μΑ | |
| | $V_R = 45 \text{ V}$ $T_A = 125 \text{ °C}$ | I _R ⁽²⁾ | 17 | 50 | mA | | |

Notes

⁽¹⁾ With heatsink

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width ≤ 40 ms



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| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | |
|---|------------|----------------|------------|------|------|--|
| PARAMETER | SYMBOL | VT3045CBP | VIT3045CBP | UNIT | | |
| Typical thermal resistance | per diode | D | 1.6 | | °C/W | |
| | per device | $R_{	heta JC}$ | 0.85 | | | |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|------------------|-----------------|--------------|---------------|---------------|--|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | |
| TO-220AB | VT3045CBP-M3/4W | 1.89 | 4W | 50/tube | Tube | | |
| TO-262AA | VIT3045CBP-M3/4W | 1.45 | 4W | 50/tube | Tube | | |

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

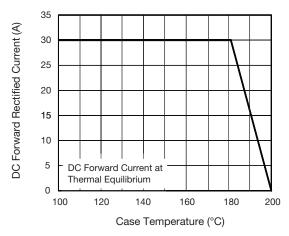


Fig. 1 - Maximum Forward Current Derating Curve

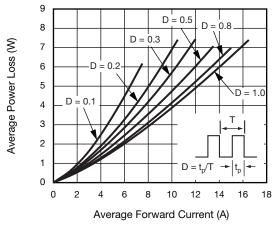


Fig. 2 - Forward Power Loss Characteristics Per Diode

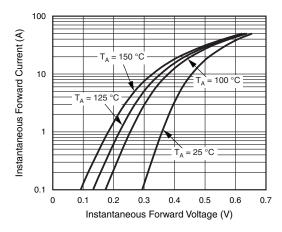


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

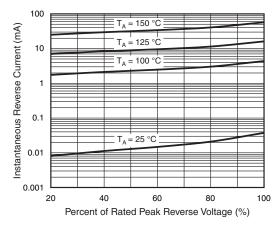


Fig. 4 - Typical Reverse Characteristics Per Diode





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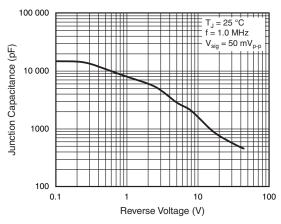


Fig. 5 - Typical Junction Capacitance Per Diode

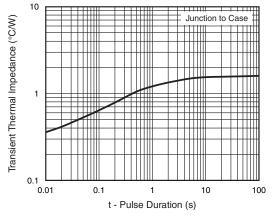
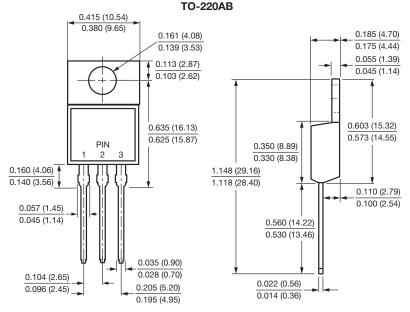
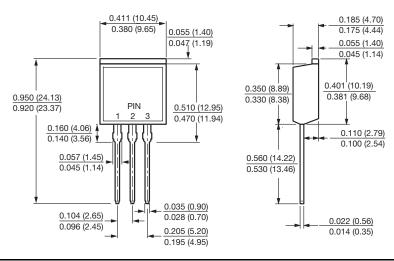


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-262AA





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